



# MOTOROLA SEMICONDUCTORS

P.O. BOX 20912 • PHOENIX, ARIZONA 85036

## Product Preview

### HIGH SPEED DUAL MOSFET DRIVER

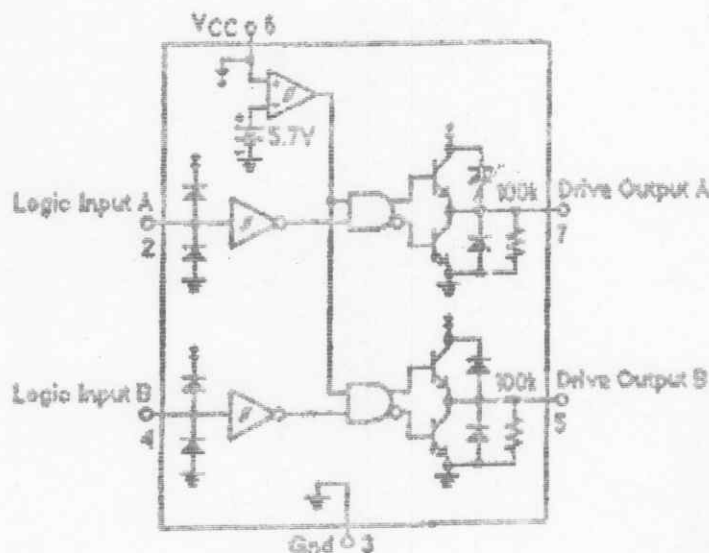
The MC34151, MC33151 is a dual inverting monolithic high speed driver specifically designed for applications that require low current digital circuitry to drive large capacitive loads with high slew rates. This device features low input current making it CMOS and LSTTL logic compatible, input hysteresis for fast output switching that is independent of input transition time, and two high current totem pole outputs ideally suited for driving power MOSFETs. Also included is an undervoltage lockout with hysteresis to prevent erratic system operation at low supply voltages.

Typical applications include switching power supplies, DC to DC converters, capacitor charge pump voltage doublers/inverters, and motor controllers.

These devices are available in dual-in-line and surface mount packages.

- Two Independent Channels with 1.5A Totem Pole Outputs
- Output Rise and Fall Times of 15nS with 1000pF Load
- CMOS/LSTTL Compatible Inputs with Hysteresis
- Undervoltage Lockout with Hysteresis
- Low Standby Current
- Efficient High Frequency Operation
- Enhanced System Performance with Common Switching Regulator Control ICs
- Pin Out Equivalent to DS0026 and MMH0026

### BLOCK DIAGRAM



**SILVERSTAR**

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**MC34151  
MC33151**

### HIGH SPEED DUAL MOSFET DRIVER

### SILICON MONOLITHIC INTEGRATED CIRCUIT

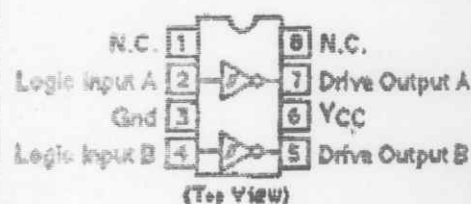
**P SUFFIX  
PLASTIC PACKAGE  
CASE 626-05**



**D SUFFIX  
PLASTIC PACKAGE  
CASE 751-02  
SO-8**



### PIN CONNECTIONS



### ORDERING INFORMATION

Device	Temperature Range	Package
MC34151D	0 to +70°C	SO-8 Plastic DIP
MC34151P	0 to +70°C	Plastic DIP
MC33151D	-40 to +85°C	SO-8 Plastic DIP
MC33151P	-40 to +85°C	Plastic DIP

**MAXIMUM RATING**

Rating	Symbol	Value	Unit
Power Supply Voltage	$V_{CC}$	20	V
Logic Inputs	$V_{in}$	-0.3 to $V_{CC}$	V
Drive Outputs (Note 1)			A
Totem Pole Sink or Source Current	$I_O$	1.5	
Upper and Lower Clamp Diode Forward Current	$I_F$	1.0	
Power Dissipation and Thermal Characteristics			
D Suffix Package SO-8 Case 751-02			
Maximum Power Dissipation @ $T_A = 50^\circ\text{C}$	$P_D$	0.56	W
Thermal Resistance Junction to Air	$R_{\theta JA}$	180	$^\circ\text{C/W}$
P Suffix 8-Pin Package Case 626-05			
Maximum Power Dissipation @ $T_A = 50^\circ\text{C}$	$P_D$	1.0	W
Thermal Resistance Junction to Air	$R_{\theta JA}$	100	$^\circ\text{C/W}$
Operating Junction Temperature	$T_J$	+150	$^\circ\text{C}$
Operating Ambient Temperature	$T_A$		$^\circ\text{C}$
MC34151		0 to +70	
MC33151		-40 to +85	
Storage Temperature Range	$T_{stg}$	-65 to +150	$^\circ\text{C}$

**ELECTRICAL CHARACTERISTICS** ( $V_{CC} = 12\text{ V}$ , For typical values  $T_A = 25^\circ\text{C}$ , for min/max values  $T_A$  is the operating ambient temperature range that applies [Note 2] unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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**LOGIC INPUTS**

Input Threshold Voltage					V
High State Logic 1	$V_{IH}$	2.6	—	—	
Low State Logic 0	$V_{IL}$	—	—	0.8	
Hysteresis	$V_H$	0.04	—	0.4	
Input Current					mA
High State ( $V_{IH} = 2.6\text{ V}$ )	$I_{IH}$	—	—	1.0	
Low State ( $V_{IL} = 0.8\text{ V}$ )	$I_{IL}$	—	—	0.1	

**DRIVE OUTPUT**

Output Voltage					V
Low State ( $I_{Sink} = 10\text{ mA}$ )	$V_{OL}$	—	0.8	1.2	
( $I_{Sink} = 50\text{ mA}$ )		—	1.1	2.0	
( $I_{Sink} = 400\text{ mA}$ )		—	1.5	2.5	
High State ( $I_{Source} = 10\text{ mA}$ )	$V_{OH}$	10.3	11.2	—	
( $I_{Source} = 50\text{ mA}$ )		10.0	11.1	—	
( $I_{Source} = 400\text{ mA}$ )		9.5	10.8	—	
Output Pull-Down Resistor	$R_{PD}$	—	100	—	k $\Omega$

**Notes:**

- Maximum package power dissipation limits must be observed.
- Low duty cycle pulse techniques are used during test to maintain the junction temperature as close to ambient as possible.

$$T_{low} = 0^\circ\text{C for MC34151}$$

$$= -40^\circ\text{C for MC33151}$$

$$T_{high} = 70^\circ\text{C for MC34151}$$

$$= 85^\circ\text{C for MC33151}$$


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## MC34151 - MC33151

**ELECTRICAL CHARACTERISTICS** ( $V_{CC} = 12\text{ V}$ , For typical values  $T_A = 25^\circ\text{C}$ , for min/max values  $T_A$  is the operating ambient temperature range that applies [Note 2] unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
<b>SWITCHING CHARACTERISTICS</b> ( $T_A = 25^\circ\text{C}$ )					
Propagation Delay (10% Input to 10% Output, $C_L = 1.0\text{ nF}$ )					
Logic Input to Drive Output Rise	$t_{PLH}(\text{IN}/\text{OUT})$	—	50	100	nS
Logic Input to Drive Output Fall	$t_{PHL}(\text{IN}/\text{OUT})$	—	45	100	
Drive Output Rise Time (10% to 90%)	$t_r$	—	9	—	nS
$C_L = 15\text{ pF}$		—	14	30	
$C_L = 1.0\text{ nF}$		—	26	50	
Drive Output Fall Time (90% to 10%)	$t_f$	—	11	—	nS
$C_L = 15\text{ pF}$		—	16	30	
$C_L = 1.0\text{ nF}$		—	28	50	
<b>TOTAL DEVICE</b>					
Power Supply Current	$I_{CC}$	—	6.0	10	mA
Standby (Logic Inputs Grounded)		—	10.5	15	
Operating ( $C_L = 1.0\text{ nF}$ Drive Outputs 1 and 2, $f = 100\text{ kHz}$ )					
Operating Voltage	$V_{CC}$	6.0	—	18	V

FIGURE 1 - SWITCHING CHARACTERISTICS TEST CIRCUIT

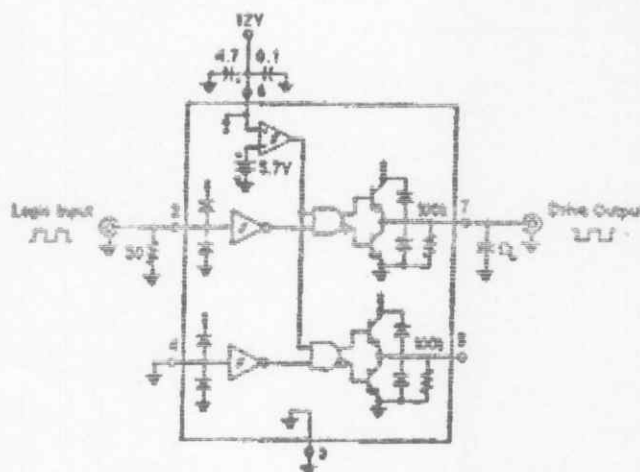
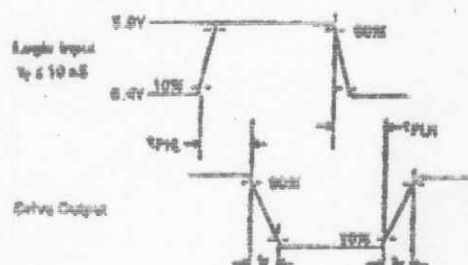


FIGURE 2 - SWITCHING WAVEFORM DEFINITIONS



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MC34151 - MC33151

FIGURE 3 - ENHANCED SYSTEM PERFORMANCE WITH COMMON SWITCHING REGULATORS

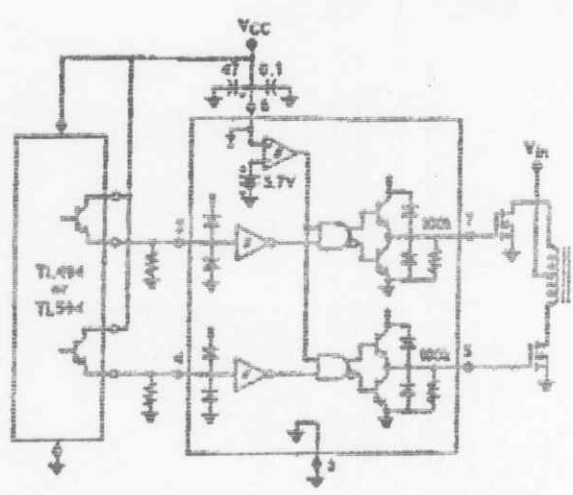


FIGURE 4 - MOSFET PARASITIC OSCILLATIONS

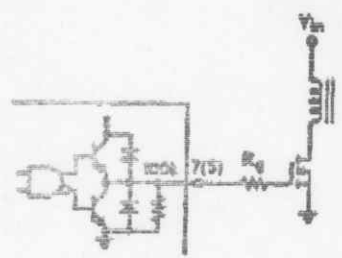


FIGURE 5 - DIRECT TRANSFORMER DRIVE

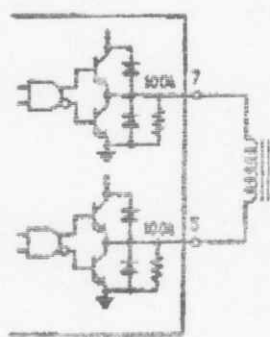
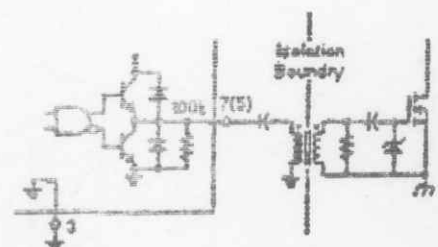
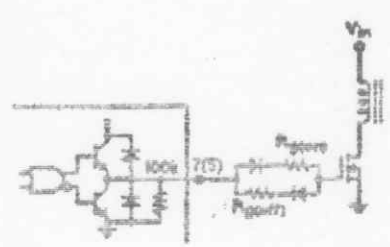


FIGURE 6 - ISOLATED MOSFET DRIVE



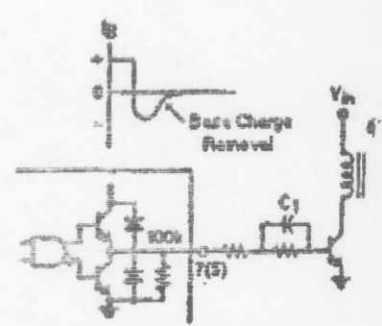
Series gate resistor  $R_g$  may be needed to damp high frequency parasitic oscillations caused by the MOSFET input capacitance and any parasitic inductance in the gate-source circuit.  $R_g$  will decrease the MOSFET switching speed.

FIGURE 7 - CONTROLLED MOSFET DRIVE



In noise sensitive applications, both conducted and radiated EMI can be reduced significantly by controlling the MOSFET's turn-on and turn-off times.

FIGURE 8 - BIPOLAR TRANSISTOR DRIVE



The totem-pole outputs can furnish negative base current for enhanced transistor turn-off, with the addition of  $C_1$ .



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